

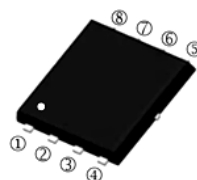
RoHS Compliant Product  
A suffix of "-C" specifies halogen & lead-free

## DESCRIPTION

The SSPR30N03S-C is the Shielded Gate Technology N-Ch MOSFETs with extreme high cell density, which provide excellent  $R_{DS(ON)}$  and gate charge for most of the synchronous buck converter applications.

The SSPR30N03S-C meet the RoHS and Green Product requirement with full function reliability approved.

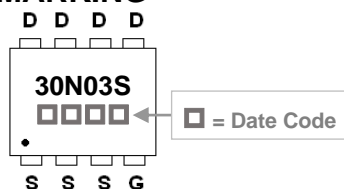
SPR-8PP



## FEATURES

- Shielded Gate Trench Technology
- Super Low Gate Charge
- Green Device Available

## MARKING

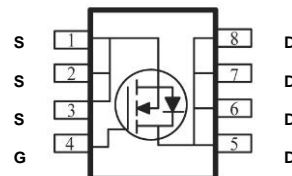


## PACKAGE INFORMATION

Package	MPQ	Leader Size
SPR-8PP	3K	13 inch

## ORDER INFORMATION

Part Number	Type
SSPR30N03S-C	Lead (Pb)-free and Halogen-free



## ABSOLUTE MAXIMUM RATINGS ( $T_A=25^\circ\text{C}$ unless otherwise specified)

Parameter	Symbol	Ratings	Unit
Drain-Source Voltage	$V_{DS}$	30	V
Gate-Source Voltage	$V_{GS}$	$\pm 20$	V
Continuous Drain Current <sup>15</sup> @ $V_{GS}=10\text{V}$	$I_D$	$T_C=25^\circ\text{C}$	30
		$T_C=100^\circ\text{C}$	19
Pulsed Drain Current <sup>2</sup>	$I_{DM}$	100	A
Power Dissipation <sup>3</sup>	$P_D$	24	W
Operating Junction & Storage Temperature Range	$T_J, T_{STG}$	-55~150	$^\circ\text{C}$
<b>Thermal Resistance Ratings</b>			
Maximum Thermal Resistance Junction-Ambient <sup>1</sup>	$R_{\theta JA}$	60	$^\circ\text{C/W}$
Maximum Thermal Resistance Junction-Case <sup>1</sup>	$R_{\theta JC}$	5.2	

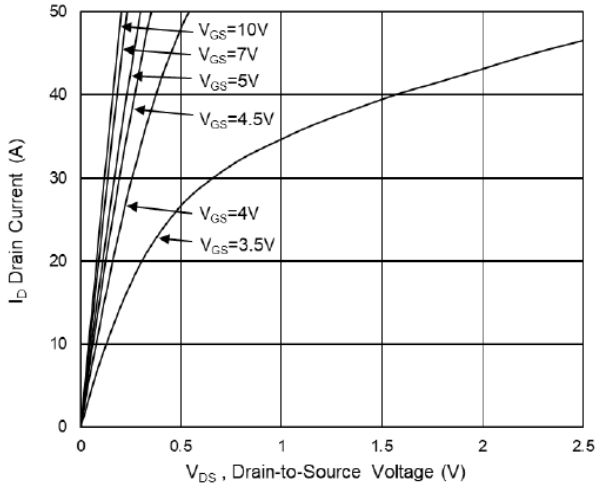
**ELECTRICAL CHARACTERISTICS** ( $T_J=25^\circ\text{C}$  unless otherwise specified)

Parameter	Symbol	Min.	Typ.	Max.	Unit	Test Conditions	
Drain-Source Breakdown Voltage	$BV_{DSS}$	30	-	-	V	$V_{GS}=0V, I_D=250\mu A$	
Gate-Threshold Voltage	$V_{GS(th)}$	1	-	2.5	V	$V_{DS}=V_{GS}, I_D=250\mu A$	
Gate-Source Leakage Current	$I_{GSS}$	-	-	$\pm 100$	nA	$V_{GS}=\pm 20V, V_{DS}=0V$	
Drain-Source Leakage Current	$I_{DSS}$	$T_J=25^\circ\text{C}$	-	-	1	$\mu A$	$V_{DS}=24V, V_{GS}=0V$
		$T_J=55^\circ\text{C}$	-	-	5		
Static Drain-Source On-Resistance <sup>2</sup>	$R_{DS(ON)}$		-	4	5.2	m $\Omega$	$V_{GS}=10V, I_D=15A$
			-	6.3	8.8		$V_{GS}=4.5V, I_D=7.5A$
Total Gate Charge (4.5V)	$Q_g$	-	8.5	-	nC	$I_D=15A$ $V_{DS}=15V$ $V_{GS}=10V$	
Total Gate Charge		-	16.5	-			
Gate-Source Charge		$Q_{gs}$	-	2.9			-
Gate-Drain Change		$Q_{gd}$	-	3.5			-
Turn-on Delay Time	$T_{d(on)}$	-	7	-	nS	$V_{DD}=15V$ $I_D=15A$ $V_{GS}=10V$ $R_G=3.3\Omega$	
Rise Time	$T_r$	-	42	-			
Turn-off Delay Time	$T_{d(off)}$	-	16	-			
Fall Time	$T_f$	-	6.2	-			
Input Capacitance	$C_{iss}$	-	882	-	pF	$V_{GS}=0V$ $V_{DS}=15V$ $f=1\text{MHz}$	
Output Capacitance	$C_{oss}$	-	380	-			
Reverse Transfer Capacitance	$C_{rss}$	-	65	-			
<b>Source-Drain Diode</b>							
Diode Forward Voltage <sup>2</sup>	$V_{SD}$	-	-	1.2	V	$I_S=1A, V_{GS}=0V, T_J=25^\circ\text{C}$	
Continuous Source Current <sup>1 4 5</sup>	$I_S$	-	-	30	A	$V_G=V_D=0V, \text{Force Current}$	

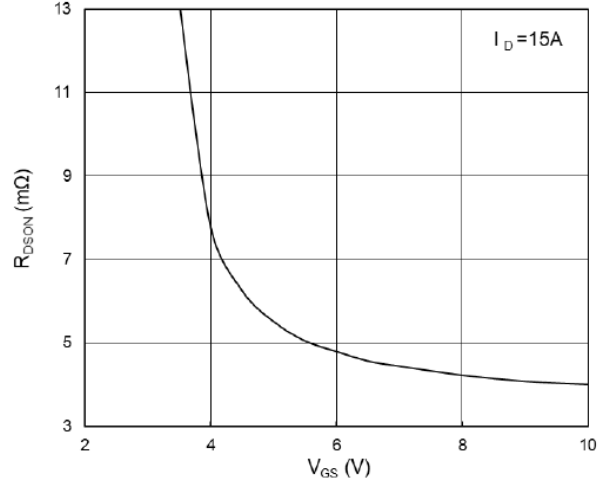
Notes:

1. The data tested by surface mounted on a 1 inch<sup>2</sup> FR-4 board with 2oz copper.
2. Single pulse width limited by junction temperature  $T_{J(MAX)}=150^\circ\text{C}$ .
3. The power dissipation is limited by  $150^\circ\text{C}$  junction temperature.
4. The data is theoretically the same as  $I_D$  and  $I_{DM}$ , in real applications, should be limited by total power dissipation.
5. The maximum current rating is package limited.

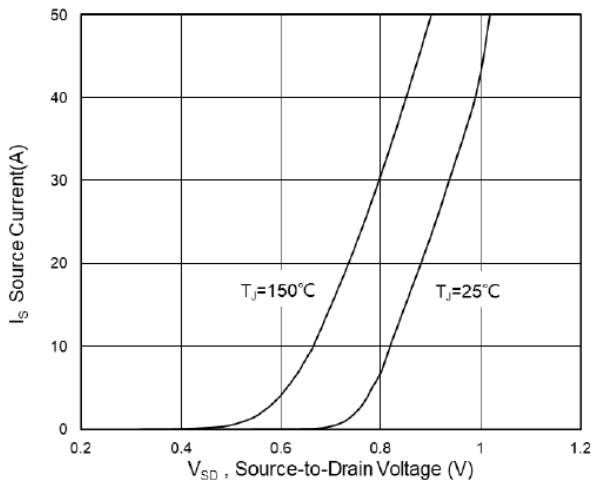
**CHARACTERISTIC CURVES**



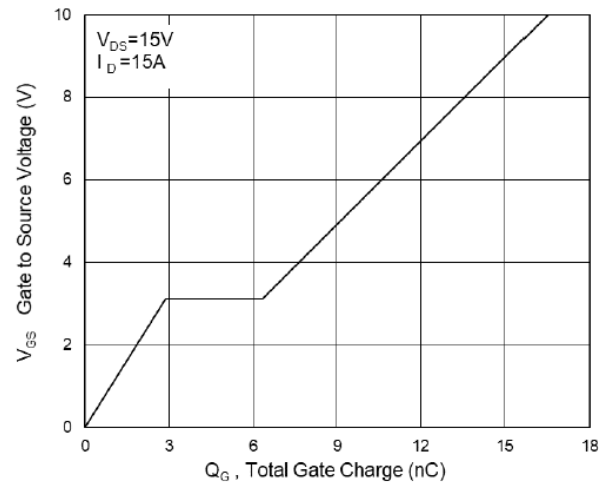
**Fig.1 Typical Output Characteristics**



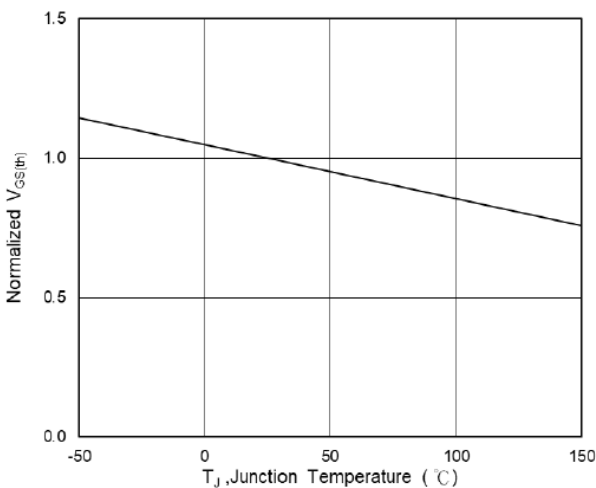
**Fig.2 On-Resistance vs G-S Voltage**



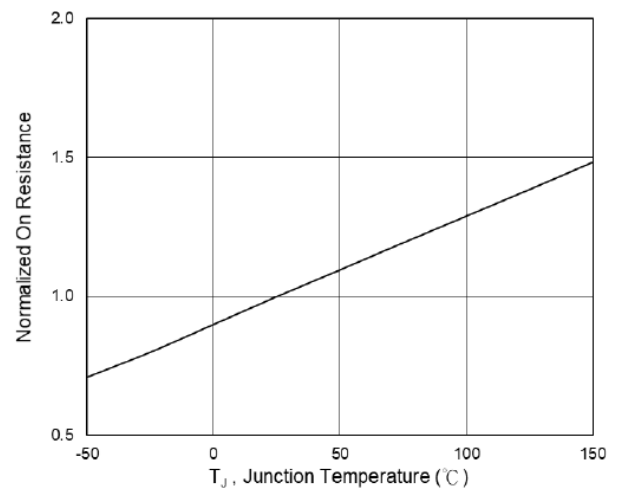
**Fig.3 Source Drain Forward Characteristics**



**Fig.4 Gate-Charge Characteristics**

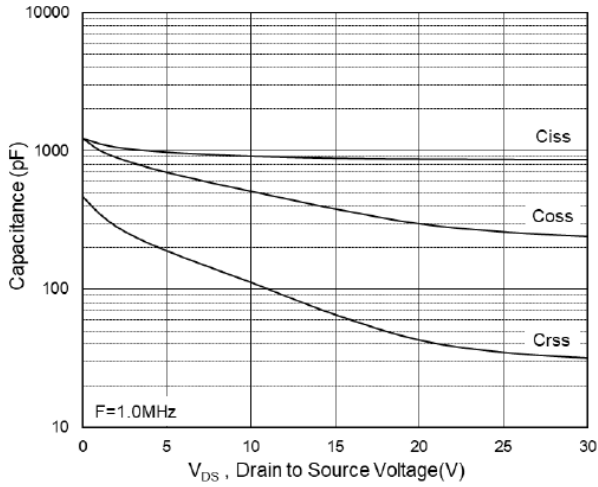


**Fig.5 Normalized  $V_{GS(th)}$  vs  $T_J$**

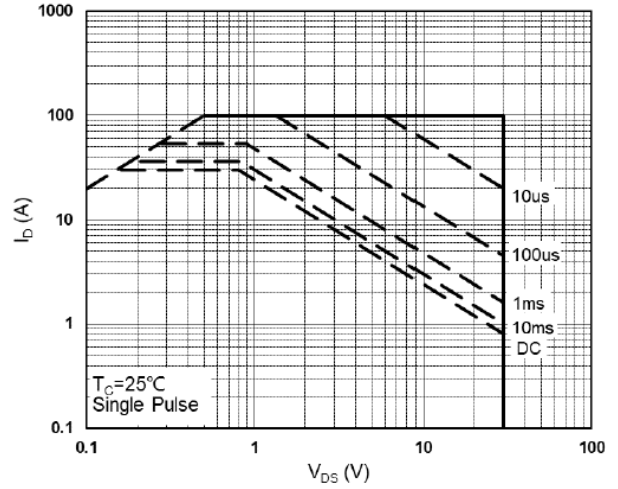


**Fig.6 Normalized  $R_{DS(ON)}$  vs  $T_J$**

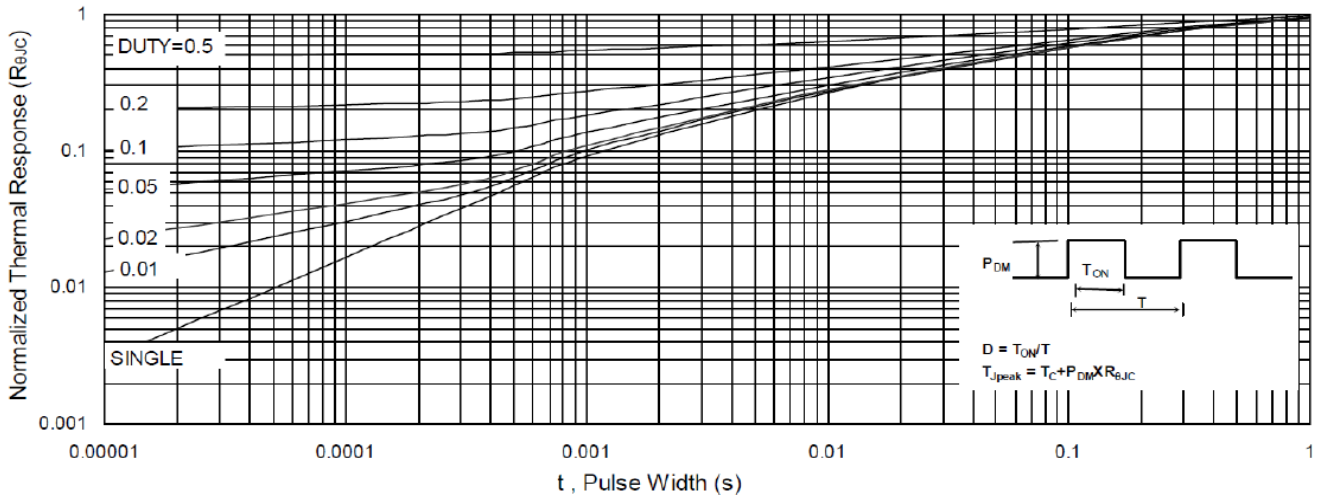
**CHARACTERISTIC CURVES**



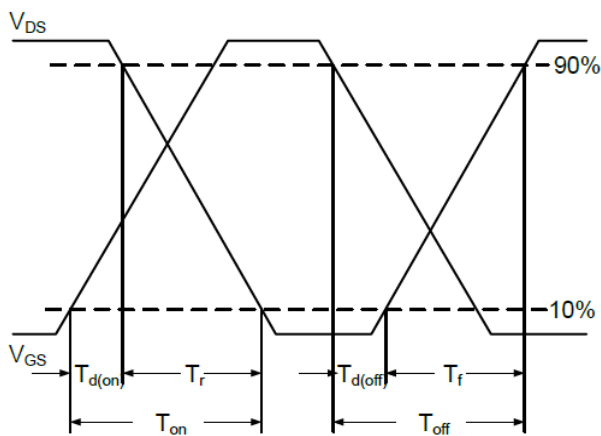
**Fig.7 Capacitance**



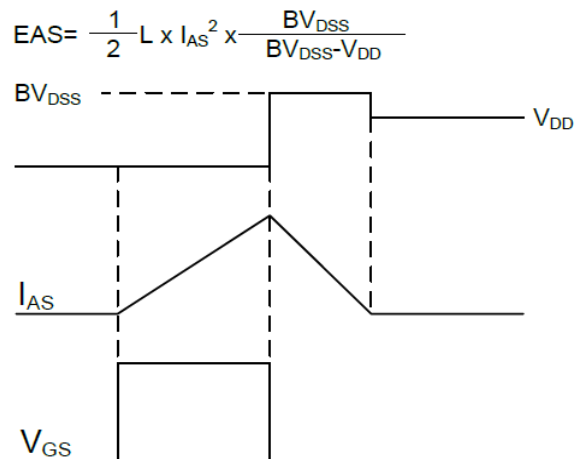
**Fig.8 Safe Operating Area**



**Fig.9 Normalized Maximum Transient Thermal Impedance**



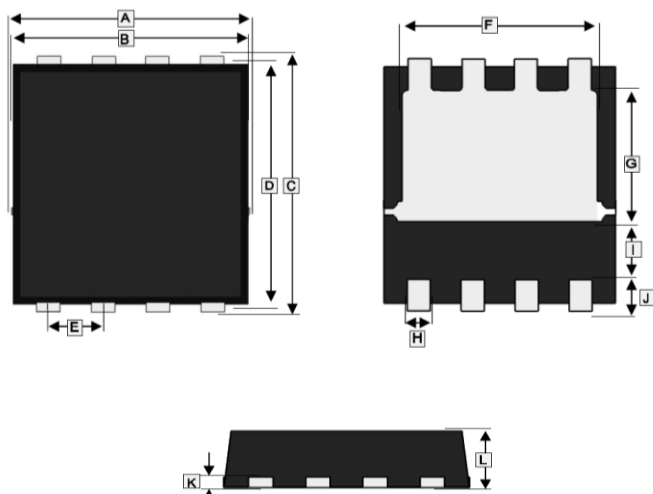
**Fig.10 Switching Time Waveform**



**Fig.11 Unclamped Inductive Waveform**

**PACKAGE OUTLINE DIMENSIONS**

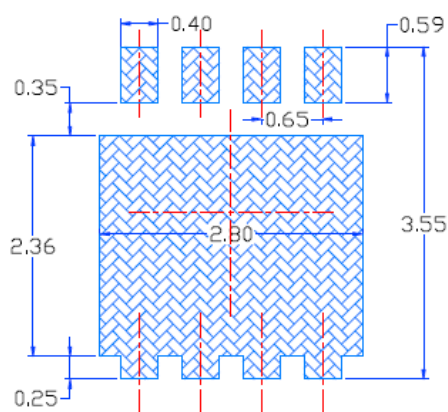
**SPR-8PP**



REF.	Millimeter	
	Min.	Max.
A	3.00	3.40
B	3.00	3.25
C	3.20	3.45
D	3.00	3.20
E	0.65 BSC.	
F	2.39	2.60
G	1.35	1.98
H	0.24	0.35
I	0.35 TYP.	
J	0.60 TYP.	
K	0.10	0.25
L	0.70	0.90

**MOUNTING PAD LAYOUT**

**SPR-8PP**



\*Dimensions in millimeters